#### **Features**

- FCC approved method of EMI attenuation
- Non-PLL phase controlled active EMI management architecture
- Generates a 1X low EMI Phase Modulated replication of the input signal
- VDD 1.65V ~ 2.0V, 20MHz to 33MHz
- VDD 2.5V ~ 3.6V, 20MHz to 55MHz
- Multiple Deviation Selections
- Minimum frequency deviation selection capability
- Power Down Mode
- 8-pin WDFN package
- Supports automotive reliability standard:
   AEC-Q100 Grade 1 and Grade 2 certified

## **Applications**

 The QE212 series is targeted towards mobile platforms such as cell phones, MIDs, Netbooks and other "power and space" sensitive applications.

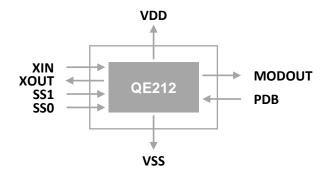
## **Product Description**

The QE212 is a versatile 1x Active EMI management IC designed to provide system wide reduction of Electromagnetic Interference (EMI) and Radio Frequency Interference (RFI) from clock and data sources. The QE212 allows significant system cost savings by reducing the number of circuit board layers, ferrite beads, shielding and other passive components that are traditionally required to pass EMI regulations.

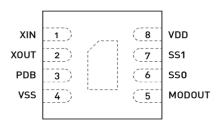
The QE212 family of mobile active EMI management ICs is unique in its design and is based on the phase controlled Active EMI management technology. This allows operation on aperiodic as well periodic signals. By the precise placement of the edges of the reconstructed input signal, the peak energy of the output is distributed over a wider and controlled energy band thereby significantly lowering system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. The QE212 has an input frequency range of 20MHz to 55MHz over a wide voltage range of 1.65V to 3.6V. The device can be placed in a "power save mode" by setting the PDB pin to GND where in it draws typically 0.1uA and also sets the MODOUT pin to a High-Z state. The device has two "deviation control pins" SS1 and SS0 to allow flexibility and optimization of both EMI compliance as well as in system design.

The device is available in 8-pin WDFN package.

## **Block Diagram**



## **Pin Configuration**





# **Pin Description**

Pin#	Pin Name	Type	Description
1	XIN	I	Crystal Oscillator Input
2	XOUT	0	Crystal Oscillator Output
3	PDB	I	Power Down pin. Active Low. Forces MODOUT to High-Z
4	VSS	Р	System ground reference input.
5	MODOUT	0	1X phase modulated buffered output.
6	SS0	I	Deviation Control Pin (refer Functionality Table) Internal Pull-Up Resistor. Recommend external Pull-Down Resistor $0\Omega$
7	SS1	I	Deviation Control Pin (refer Functionality Table) Internal Pull-Down Resistor Recommend external Pull-Up Resistor 0Ω
8	VDD	0	System Power Supply pin

# **Operating Conditions**

Parameter	Description	Min	Max	Unit
VDD <sub>(3.3V)</sub>	Supply Voltage	1.65	3.6	V
T <sub>A</sub>	Operating Temperature (Ambient Temperature)	-40	+125	°C
$C_L$	Load Capacitance		20	pF
C <sub>IN</sub>	Input Capacitance		5	pF
Note: Please re	efer to ordering information for T <sub>A</sub>			

# **Absolute Maximum Rating**

Symbol	Parameter	Rating	Unit
$V_{in}$	Voltage on any pin with respect to Ground	-0.5 to +4.6	V
T <sub>STG</sub>	Storage temperature	-65 to +125	°C
T <sub>s</sub>	Max. Soldering Temperature (10 sec)	260	°C
$T_J$	Junction Temperature	150	°C
$T_DV$	Static Discharge Voltage (As per JEDEC STD22- A114-B)	2	KV
Note: These a	re stress ratings only and are not implied nor quaranteed for functional use. F	vnosure to absolute m	aximum ratings

Note: These are stress ratings only and are not implied nor guaranteed for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability.

# **Functional Table**

	Freq.	Гиол				Deviati	ion (%)					
VDD (V)	Range	Freq. (MHz)	SS1	SS0	SS1	SS0	SS1	SS0	SS1	SS0		
	(MHz)	(1411 12)	0	0	0	1	1	0	1	1		
		20	±0	.05	±0	.10	±0	±0.14		.18		
1.0	20 ~ 33	24	±0	±0.06		±0.12		±0.15		-		
1.8		27	±0.07		±0.13		±0.13		-			
		33	±0.08		±0.08		-		-			±0.18 ±0.14 ±0.16
		20	±0.04		±0	±0.08		.10	±0.	.14		
3.3	20 ~ 55	24	±0	.05	±0	±0.10		±0.13		.16		
3.3	20 ~ 55	48	±0	.10	±0	±0.18		±0.22		-		
		54	±0.12		±0.18		±0.21		-			
Note: Frequence	cy deviation can	vary over v	oltage and	temperatu	re by ±20%							



# DC Electrical Characteristics (3.3 +/-0.3V)

Parameter	Description	Test 0	Conditions	Min	Тур	Max	Unit	
VDD	Supply Voltage			3.0	3.3	3.6	V	
$V_{IH}$	Input HIGH Voltage			0.66 * VDD			V	
$V_{IL}$	Input LOW Voltage					0.33 * VDD	V	
I <sub>IH</sub>	Input HIGH Current (pin 5 and 6)	V <sub>IN</sub> = VD	D			10	μΑ	
I <sub>IL</sub>	Input LOW Current (pin 5 and 6)	$V_{IN} = 0V$				10	μA	
V <sub>OH</sub>	Output HIGH Voltage	$I_{OH} = -8n$	nA	0.75 * VDD			V	
$V_{OL}$	Output LOW Voltage	$I_{OL} = +8r$	nΑ			0.25 * VDD	V	
I <sub>CC</sub>	Static Supply Current	PDB = V	'SS		0.1	1.0	μA	
	Dynamic Supply Current	27MHz	Unloaded		7.0	8.0	mA	
I <sub>DD</sub>	(SS1=1, SS0=1)	ZIIVINZ	10pF load		8.0	9.0	ША	
Z <sub>0</sub>	Output Impedance				25		Ω	

# **Switching Characteristics (3.3V +/-0.3V)**

Parameter	Description	Description Test Conditions				Unit
INPUT	Input Frequency		20	24	55	MHz
MODOUT	Output Frequency		20	24	55	MHz
T <sub>d</sub>	Duty Cycle <sup>1,2</sup> = $(t_2/t_1)*100$	Measured at VDD/2	45	50	55	%
t <sub>3</sub>	Output Rise Time 1,2	Measured between 20% to 80%	0.6	1.5	2.5	nS
t <sub>4</sub>	Output Fall Time 1,2	Measured between 80% to 20%	0.6	1.4	2.5	nS
$t_J$	Cycle-to-cycle jitter <sup>2</sup>	Unloaded outputs 27MHz		±250		pS

#### Note:

# DC Electrical Characteristics (1.8 +/-0.15V)

Parameter	Description	Test (	Conditions	Min	Тур	Max	Unit	
VDD	Supply Voltage			1.65	1.8	1.95	V	
$V_{IH}$	Input HIGH Voltage			0.66 * VDD			V	
$V_{IL}$	Input LOW Voltage					0.33 * VDD	V	
I <sub>IH</sub>	Input HIGH Current (pin 5 and 6)	V <sub>IN</sub> = VD	DD			10	μA	
I <sub>IL</sub>	Input LOW Current (pin 5 and 6)	V <sub>IN</sub> = 0V				10	μΑ	
$V_{OH}$	Output HIGH Voltage	$I_{OH} = -4n$	nA	0.75 * VDD			V	
$V_{OL}$	Output LOW Voltage	$I_{OL} = +4r$	mA			0.25 * VDD	V	
I <sub>cc</sub>	Static Supply Current	PDB = V	'SS		0.1	1.0	μA	
1	Dynamic Supply Current	27MHz	Unloaded		3.0	4.0	mA	
I <sub>DD</sub>	(SS1=1, SS0=1)	ZINITZ	10pF load		3.5	4.5	ША	
$Z_0$	Output Impedance				25		Ω	

<sup>1.</sup> All parameters specified with loaded outputs.

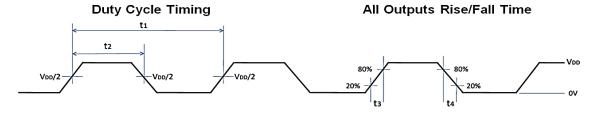
<sup>2.</sup> Parameter is guaranteed by design and characterization. Not 100% tested in production.

# **Switching Characteristics (1.8 +/-0.15V)**

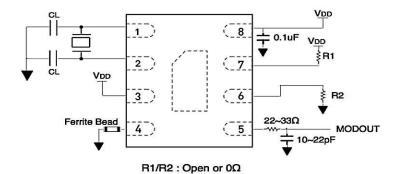
Parameter	Description	Test Conditions	Min	Тур	Max	Unit
INPUT	Input Frequency		20	24	33	MHz
MODOUT	Output Frequency		20	24	33	MHz
$T_d$	Duty Cycle <sup>1,2</sup> = $(t_2/t_1)*100$	Measured at VDD/2	45	50	55	%
t <sub>3</sub>	Output Rise Time 1,2	Measured between 20% to 80%	0.8	1.5	1.8	nS
t <sub>4</sub>	Output Fall Time 1,2	Measured between 80% to 20%	0.8	1.0	1.8	nS
$t_J$	Cycle-to-cycle jitter <sup>2</sup>	Unloaded outputs 27MHz		±250		pS

#### Note:

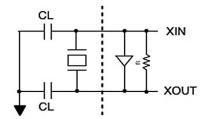
- 1. All parameters specified with loaded outputs.
- 2. Parameter is guaranteed by design and characterization. Not 100% tested in production.



# **Application Schematic**



# **Crystal Oscillator Circuit**



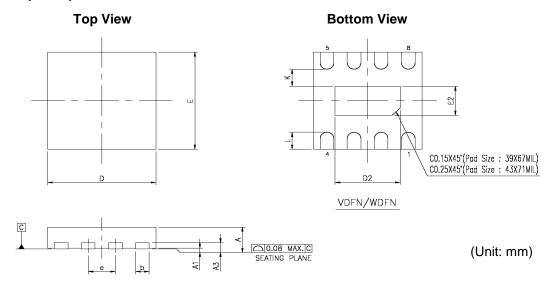
CL = 2x(Cp-Cs)
Cp: load capacitance of Crystal

Cs: Stray capacitance (PCB trace + Input cap. of IC)

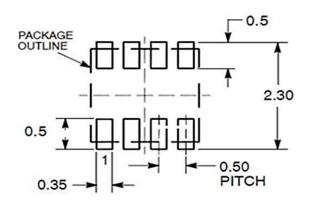
# **Ordering Information**

Part Number	Temp. Grade Indicator	· I IAMN Grade I			
QE212C	С	Commercial	0°C ~ +70°C		
QE212 I	I	Industrial	-20°C ~ +85°C		
QE212E	Е	AEC-Q100, Grade 2	-40°C ~ +105°C		
QE212A	A	AEC-Q100, Grade 1	-40°C ~ +125°C		

# Package Dimension WDFN (X208)



#### **Recommended footprint**



JEDEC OUTLINE	MO-229								
PKG CODE	WD	WDFN(X208)							
SYMBOLS	MIN.	NOM.	MAX.						
А	0.70	0.75	0.80						
A1	0.00	0.02	0.05						
А3	0.	EF.							
b	0.20	0.25	0.30						
D	2	.00 BS	C						
Е	2	.00 BS	iC						
е	0.50 BSC								
K	0.20	)   -   -							

				D2			E2			L		LEAD FINISH		JEDEC CODE	VDFN	WDEN	HDEN	TDFN	TDFN
	PAD SIZ	Ε	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	Pure Tin	PPF	OLDEC CODE	VUIN	WOIN			OPTION 2
<u> </u>	39*X67* MI	L	1.15	1.20	1.25	0.60	0.65	0.70	0.20	0.35	0.45	V	X	N/A	V	V			

<sup>&</sup>quot;\*" is an universal character, which means maybe replaced by specific character, the actual character please refers to the bonding diagram.

(Unit: mm)

Rev. 1.03 Page 5 www.qstproducts.com